

1/f Spin Noise and a Single Spin Detection with STM

YISHAY MANASSEN^{a,*} AND ALEXANDER V. BALATSKY^b

^aDepartment of Physics and the Ilse Katz Center for Nanometer Scale Science and Technology, Ben-Gurion University of the Negev, Be'er Sheva 84105, Israel

^bTheoretical Division, Los Alamos National Laboratory, Los Alamos, New Mexico 87545, USA

(Received 20 December 2003)

Abstract. We propose a novel mechanism for single spin detection based on the 1/f spin current noise. We postulate that the 1/f spin noise for the tunneling current is similar to the ubiquitous 1/f noise in magnetic systems. Magnetic coupling between tunneling electrons and localized spin **S** then leads to the peak at Larmor frequency in the power spectrum of the electric current fluctuations I_{ω}^2 . The elevated noise in the current spectrum will be spatially localized near the magnetic site. The difference in the power spectra taken at the Larmor frequency and elsewhere would reveal the peak in the spectrum. We argue that the signal-to-noise ratio for this mechanism is on the order of one. In addition, we discuss the asymmetric line shapes observed regularly with this measurement. We show that such line shapes are in accordance with the random sampling done with the tunneling electrons. Yet this predicts a line width at least one order of magnitude larger than observed experimentally, which is likely to be due to electrostatic repulsion between the tunneling electrons and temporal correlations in the tunneling process.

1/f SPIN NOISE

The phenomenon of 1/f (flicker) noise has been known for 80 years.¹ It describes the deviation from the flat spectral density expected from a current made of uncorrelated charge carriers at low frequencies. In this range, the spectral density was found to obey a power law of the form $1/f^{\alpha}$ where f is the frequency, and $\alpha = 0.5$ – 1.5 . Flicker noise appears in a multitude of electronic devices, in music,² in ocean streams,^{3,4} and in many entirely different systems. This is one of the most universal phenomena, yet one of the largest enigmas in the physical sciences.

An early explanation for this phenomenon was that the 1/f noise can arise from a superposition of relaxation processes.⁵ In this model the noise is described as a superposition of consecutive random events, each starting at a certain time t_0 and following a simple exponential relaxation law: $N(t - t_0) = N_0 e^{-(t-t_0)/\tau}$, where N is the measured quantity and τ is the relaxation time. The power spectrum of one such event is a Lorentzian. The power spectrum of a large number of such consecutive random events, all with the same τ , is also a Lorentzian.

If, on the other hand, there is a distribution of relaxation times $P(\tau) \sim 1/\tau$, from τ_1 to τ_2 , then the overall spectral density will obey a power law $\sim 1/f$ in the range between τ_1^{-1} and τ_2^{-1} . A common denominator of many mechanisms proposed for different 1/f phenomena^{6,7} is a distribution of relaxation times.

1/f noise is ubiquitous in scanning tunneling microscopy (STM) tunneling current, although its origins are not fully understood.^{8–11} Unlike the well-known shot noise, 1/f noise is proportional to the square of the current such that: $\langle I^2(\omega) \rangle / I^2 = \text{const}$. Where $\langle I^2(\omega) \rangle$ is the spectral density of current fluctuations (in units of A^2/Hz) and I is the current. Empirically, the current fluctuations in 1/f noise are known to obey the Hooge formula¹² $\langle I^2(\omega) \rangle / I^2 = a/(fN)$, where N is the number of current carriers in the sample and a is of the order of 0.01. The appearance of 1/f noise in the STM is a surprising observation because the normal “explanation” of this noise is a fluctuating defect with a wide distribution of relaxation times. Such explanations are

*Author to whom correspondence should be addressed. E-mail: manassen@bgumail.bgu.ac.il

not suitable here because of the extremely local nature of the measurement. The STM measurements of $1/f$ noise (in a voltage of -0.5V) gives a peak at zero frequency where the intensity of the current noise $\langle I^2(\omega) \rangle$ is 20 times larger than the thermal (Nyquist) noise, which will give the order of magnitude of the noise in higher frequencies (at room temperature) and amounts to $41fA/\sqrt{Hz}$. The width of the observed $1/f$ noise peak at zero frequency is of the order of 10–100 kHz.

A special case of $1/f$ noise relevant to the present paper is the magnetic flicker noise. In this case the noise is due to fluctuations in the magnetization. Normally, it is assumed that these fluctuations constitute an additional noise source in any magnetic system. However, low-frequency magnetic noise is hard to observe experimentally, and sensitive detection techniques and special systems are required. Such fluctuations were detected for the first time in spin glasses with a SQUID magnetometer.^{13,14} They were detected with SQUID also in antiferromagnetic thin films¹⁵ and on superparamagnetic nanoparticles.¹⁶ Other ways to detect $1/f$ magnetic noise is by following the resistance fluctuations close to a certain ferromagnetic transition (colossal magnetoresistance),¹⁷ and to observe the electrical noise generated in small Hall probe contacts.¹⁸ The $1/f$ noise generated in the Hall contacts is much larger than the usual $1/f$ noise measured in the same system that is unrelated to magnetic fluctuations. Despite the failure to measure spatial correlations, it is obvious¹⁸ that there is a certain coherence length such that two noise measurements done at a distance smaller than this length will give the same results.

Although we have no direct experimental evidence, we claim that since conduction electrons in metals also constitute a (special) magnetic system, there should be $1/f$ magnetic fluctuations also in the spins in such a system that is also paramagnetic. Electron spin resonance (ESR) of conduction electrons has been known for many years.^{19,20} These spectra are known for their special line shape²¹ and for the narrow lines (T_1 and T_2 are equal and large). We would like to emphasize that the sequence of individual dephasing events that are responsible for T_2 relaxation of conduction electrons are very similar to the sequence of relaxation events that are responsible for $1/f$ noise in general. Therefore, there are distributions of relaxation times that are expected to give $1/f$ magnetic fluctuations in conduction electrons in metals.

Such $1/f$ magnetic noise is expected to be of general significance in spintronics applications. We discuss here the implications of such $1/f$ magnetic noise (either in the spins of the conduction electrons or in a regular paramagnetic system) on single precessing spin detec-

tion with STM (ESR-STM). It will be shown below that this $1/f$ spin noise explains the observation of the signal from nonmagnetic tips and elucidates several aspects of this technique. We find that the interaction of the tunneling electron spins with the local impurity spin simply couples the $1/f$ magnetic noise with the noise of the local spin S , thus creating a peak in the current noise at Larmor frequency.

ESR-STM (Fig. 1) is a technique that is using the extremely local nature of the STM measurement to detect the precession of isolated spin centers on the surface. When a tip of a scanning tunneling microscope is located above a paramagnetic spin center (in the presence of an external magnetic field), the tunneling current is modulated by the precession. It was shown^{22,23} that the AC current at the Larmor frequency is spatially localized within 0.5–1 nm. It is the spatial localization that indicates (though it must be proved) that this technique is capable of detecting a single spin. In addition, it was proved that the frequency of the signal is dependent in real time on the size of the magnetic field.^{24,25} Similar experiments have been done on the paramagnetic BDPA molecule.²⁶ A very recent paper shows that ESR-STM can be done also on a TEMPO molecule, revealing the hyperfine spectrum.³⁹ The interest in this technique has risen sharply recently due to the possibility to manipulate and detect a single spin^{27,33} and due to the possibility to use it for quantum computation.^{27,28} There have been many proposals for the mechanism of this phenomenon.^{29–36} However, an experimental verification for any of the proposals is still required.

In our previous papers^{30,31} we discussed the following question: What is the role of the Heisenberg exchange interaction in ESR-STM? Under which circumstances can a tip emitting tunneling electrons with a random spin orientation create an elevated noise level at the Larmor frequency through interaction with the single precessing spin?

We argued^{30,31} that existence of long time correlations in the temporal spin polarization of tunneling current is sufficient to provide the elevated noise at the Larmor frequency in the current noise. Here we further build upon this idea and show that the $1/f$ noise in the tunneling spin current is sufficient to produce the effect. We stress that no correlations in the spin polarization of the tunneling electrons within the precession period is required to produce the elevated noise at Larmor frequency in this approach.

We discuss the spin-dependent tunneling matrix element:

$$G = G_0 \exp[-[(F - JS(t) \cdot s(t))/F_0]] \quad (1)$$

s is a spin matrix with implicit spin indices that are given

by conduction electron spin operator $\mathbf{s}^i = 1/2 \boldsymbol{\sigma}_{\alpha\beta}^i$, $i = x, y, z$, $\mathbf{S}(t)$ is the local impurity spin. In an external magnetic field it will have random dynamics, with a remnant of the precession at the Larmor frequency. F is the barrier height (typically 4 eV), J is the exchange coupling, and F_0 is the energy related to the distance d between the tip and the surface: $F_0 = d^2/8md^2$. In this term, the tunneling probability depends on the relative orientation between $\mathbf{S}$ and $\mathbf{s}$ (Fig. 1). We write:

$$G = G_0 \exp[-(F/F_0)] (\cosh[(JS/2F_0) + \mathbf{s}(t) \cdot \mathbf{n}(t) \sinh(JS/2F_0)] \quad (2)$$

Where $\mathbf{n}$ is a unit vector in the direction of $\mathbf{S}$.

The Hamiltonian we consider describes a spin-dependent tunneling matrix element between the tip (L electrode) and the surface (R electrode):

$$H = \sum_{\mathbf{k}, \alpha} \epsilon(\mathbf{k}) c_{L\alpha}^\dagger(\mathbf{k}) c_{L\alpha}(\mathbf{k}) + (L \rightarrow R) + \sum_{\mathbf{k}, \mathbf{k}'} c_{L\alpha}^\dagger(\mathbf{k}) G_{\alpha\beta} c_{R\beta}(\mathbf{k}') \quad (3)$$

We assume that the magnetic field is along the z axis: $B \parallel z$ with corresponding Larmor frequency $\omega_L = g\mu_B B$. The tunneling current operator will contain the spin-independent part that we omit hereafter and the spin-dependent part:

$$\delta \hat{I}(t) = G_1 \mathbf{n}(t) \mathbf{I}_s(t) \quad (4)$$

where $G_1 = G_0 \exp[-(F/F_0) \sinh(JS/2F_0)]$, and $\mathbf{I}_s(t)$ is a spin current between tip and substrate. The dc current at a given bias V is: $I_0 = g_0 V$, $g_0 = G_0 \exp[-(F/F_0) \cosh(JS/2F_0)]$. The current-current correlator, normalized to dc current, is then

$$\frac{\langle \delta \hat{I}(t) \delta \hat{I}(t') \rangle}{I_0^2} = [\sinh(JS/2F_0)]^2 \times \sum_{i,j=x,y,z} \langle n^i(t) n^j(t') \rangle I_s^i(t) I_s^j(t') \quad (5)$$

More rigorous treatment, similar to the one done in ref 37, where one takes into account the effect of the local spin on the mass current in the ignored terms, will lead to the contribution of the same order as the term we are focusing on. Hence we use a simplified formula for the current that gives the right order of magnitude estimate.

The change in the tunneling conductance due to exchange interaction between the tunneling electrons and the localized spin leads to eq 4: $\delta \hat{I}(t) \sim \mathbf{I}_s(t) \cdot \mathbf{S}(t)$. Only the transverse components contribute to this term ($S_x(t)$ and $S_y(t)$). When the spins of the tunneling electrons are completely uncorrelated we can say that the dispersion

of the tunneling current which is dependent on the spin (over one precession period T) is: $\sum_i \langle \delta I^2 \rangle \sim \sum_{i=1}^N (s_x(t_i) I_{s,x}(t_i))^2 + (x \rightarrow y) \sim \langle N \rangle$. Or, the relative dispersion compared with the tunneling current will be: $\langle I^2 \rangle / I^2 \sim 1/\langle N \rangle$. To estimate the magnitude of the spin-dependent dispersion, namely the size of the noise that is due to the interaction with the precessing spin, we use:

$$(\langle I^2 \rangle)^{1/2} / I_0 \sim 2/N \sinh[(JS/2F_0)] \quad (6)$$

If we take a typical value of $J = 0.1$ eV, $F = 4$ eV, $F_0 = 0.1$ eV (for $d = 4\text{\AA}$), and $S = 1/2$, we get a value of 0.01, namely rf intensity of 10 picoamperes, which is within the right order of magnitude.

The spectrum is detected at the frequency domain, and by looking at the Fourier transform of the current fluctuations. This means that the spectrum is a convolution of the power spectrum of the single spin fluctuations: $\langle S_i^2(\omega) \rangle = \frac{\gamma}{[(\omega - \omega_L)^2 + \gamma^2]}$ and the power spectrum of the spin tunneling current: $\langle I_{s,i}(\omega) I_{s,j}(-\omega) \rangle = \delta_{ij} \langle I_s^2(\omega) \rangle$. Here, to be specific, we assumed the spectrum of a localized spin to be Lorentzian; however, the argument is applicable to the case of the general spectrum $\langle S_i^2(\omega) \rangle$.

$$\frac{\langle I_s^2(\omega) \rangle}{I_0^2} = [\sinh(JS/2F_0)]^2 \times \sum_{i=x,y,z} \int \frac{d\omega_1}{2\pi} \langle (I_s^i)_{\omega-\omega_1}^2 \rangle \langle (S^i)_{\omega_1}^2 \rangle \quad (7)$$

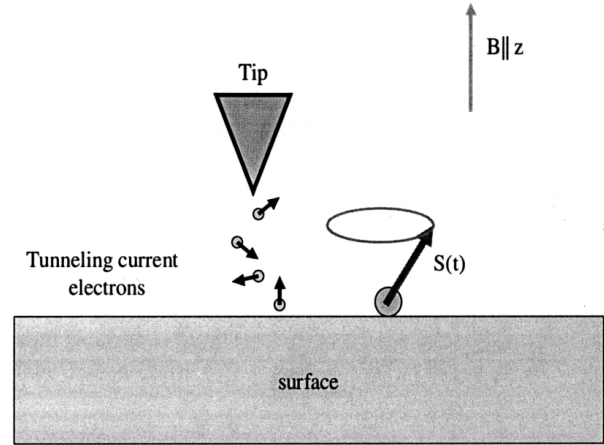


Fig. 1. Schematics of the ESR-STM experiment is shown. The fluctuations in the spin polarization of the tunneling electrons at the timescale of the precession T will be nonzero and will scale as $\frac{1}{N}$. Once the tip is positioned close to the localized spin, the exchange interaction between the localized spin and the tunneling electrons will modulate the tunneling current. The conditions in which this random modulation of the spin tunneling current with $1/f$ spectrum will create a ω_L peak are discussed in the text.

If the tunneling electron spins are completely uncorrelated, then the power spectrum is white noise, and the expected signals will be scattered over the whole frequency range. In order to get a peak at the Larmor frequency, some correlation at zero frequency is required, namely the tunneling electron spins must have some temporal spin polarization in the long time limit.³⁵

To give an example, we consider the case where several magnetic atoms are adsorbed on the tip. Then the spins of the tunneling electrons will be under the influence of slowly changing spins $\mathbf{h}_i$ of magnetic atoms due to exchange interaction $H_{int} = \sum_i J_i \mathbf{h}_i(t) \boldsymbol{\sigma}(t) = \mathbf{H}(t) \boldsymbol{\sigma}(t)$, where J_i are the exchange couplings to the i th atom and we define $\mathbf{H}$ as a sum of random fluctuating magnetic moments $\mathbf{h}_i$ of individual magnetic impurities adsorbed on the tip. Here we assume that only the "field" value $\mathbf{H}$ at the end of the tip matters, as the tunneling electrons are affected by this field the most before tunneling out of the tip. This fluctuating exchange field will spin polarize the tunneling current. The correlator is $\langle \mathbf{H}(t) \mathbf{H}(t') \rangle = \sum_i \langle \mathbf{h}_i(t) \mathbf{h}_i(t') \rangle$. The correlation function from each impurity, assuming they are independent, obeys $\langle \mathbf{h}_i(t) \mathbf{h}_i(t') \rangle = e^{-(t-t')/\tau_i}$. Averaging over distribution times t_i , with probability distribution $P(\tau) \sim 1/\tau$ between τ_1 and τ_2 , will yield the $1/f$ noise for the field fluctuation power spectrum. This follows directly from evaluating the Lorentzian in frequency space $\frac{\tau}{\omega^2 \tau^2 + 1}$, averaged over distribution of relaxation time τ with $P(\tau)$; e.g., see ref 7:

$$\langle \mathbf{H}^2(\omega) \rangle = \int_{\tau_1}^{\tau_2} d\tau \exp(i\omega(t-t')) P(\tau) \langle \mathbf{h}_i(t) \mathbf{h}_i(t') \rangle \sim \frac{1}{\omega} \quad (8)$$

Hence the tunneling current will acquire spin polarization fluctuations. It is natural to assume that the spin fluctuations of the tunneling electrons will be proportional to the fluctuating exchange field $\mathbf{H}$. The degree of spin polarization of the tunneling electron is proportional to the Zeeman energy $(g\mu_B \mathbf{H})/W$ related to the total bandwidth $W \sim 1/N_0$. We get

$$\mathbf{I}_s(t) = Ig\mu_B \mathbf{H}(t) N_0 \quad (9)$$

Here we assumed that the effect is proportional to the tunneling current I . Indeed, tunneling electrons will sample the random field $\mathbf{H}$ at a rate at which they tunnel and this rate is given by the electric current I .

We now consider the specific case when spin tunneling current has $1/f$ noise component.

$$\langle I_s^2(\omega) \rangle = \frac{C}{|\omega|}, C = aI^2 \quad (10)$$

for all components $i = x, y, z$. The magnitude of the $1/f$ noise is to be given by I^2 up to an unknown numerical

factor a ,¹² where N is absorbed in a . $1/f$ noise is peaked at zero frequency and will provide a peak at the Larmor frequency in the convolved spectrum, eq 7. We also remark here that in a similar fashion one can get the $1/f$ noise in the spin current due to $1/f$ noise in the electronic current in a presence of a constant polarizing field. We will not consider this possibility here.

Spin tunneling current will have white noise asymptotic at high frequencies. At lower frequencies, similar to the unpolarized electric current,⁸⁻¹¹ the relaxation processes that control spin relaxation in the current will contribute. To give a physically plausible argument about the origin of the $1/f$ noise consider relaxation time of the tunneling spin current:

$$\langle I_{s,i}(t) I_{s,j}(t') \rangle = \delta_{ij} \exp(-|t-t'|/\tau) \quad (11)$$

This correlation function leads to the Lorentzian for the noise spectrum with the width $\gamma = 1/\tau$: $\langle I_{s,x}^2(\omega) \rangle \propto \frac{\gamma}{\pi(\omega^2 + \gamma^2)}$. Now we assume that there is a distribution of relaxation times with probability distribution $P(\tau) d\tau$. The possible origins of the distribution of relaxation times in tunneling current can be the multiple other spins in the vicinity and in the tip that produce spin relaxation with different times. To obtain $1/f$ noise in the current correlator, one has to assume that $P(\tau) \sim 1/\tau$ in some window of relaxation times, as was mentioned earlier.

The power spectrum of the electric current, using eq 10, is:

$$\frac{\langle I_\omega^2 \rangle}{I^2} = (\sinh[\frac{JS}{2F_0}])^2 \sum_{i=x,y,z} \int \frac{d\omega_1}{2\pi} \frac{1}{|\omega - \omega_1|} \langle (S^i)_{\omega_1}^2 \rangle \simeq \frac{(\sinh[\frac{JS}{2F_0}])^2}{[(\omega - \omega_L)^2 + \gamma^2]^{1/2}} \quad (12)$$

where we used the low-frequency asymptotics for spin current eq 10 and assumed the Lorentzian for spin correlation function. We get, finally,

$$\frac{\langle I_\omega^2 \rangle}{I^2} \simeq a/\pi \frac{1}{((\delta\omega)^2 + \gamma)^{1/2}} \quad (13)$$

where we introduced the detuning parameter $\delta\omega = \omega - \omega_L$.

The signal-to-noise ratio is controlled by the parameter a and is

$$\frac{\langle I_\omega^2 \rangle}{I^2} \simeq \frac{a}{\gamma\pi} \quad (14)$$

Without the microscopic model it is impossible to know exactly what is the magnitude of a, N, ϵ . Self-consistent treatment would give the scattering rate $\gamma \sim 10^6$ Hz, which will be determined by the maximum of the intrinsic decay due to back action or the extrinsic decay due to environment. As guidance we take available STM data for the tunneling current noise.⁸⁻¹¹ In these data the $1/f$

noise is clearly seen above the high-frequency noise floor below 100 kHz. From the Hodge formula we estimate $a \sim 10^{-2}$. We take $N \sim 10$, similar to the mass current case, as estimated in ref 11. It is convenient to relate the power spectrum of the current fluctuation at the peak at $\omega = \omega_L$ to the shot noise power spectrum $\langle I_{shot}^2(\omega) \rangle = eI$. S/N ratio in this case is bound from above by the number on the order of unity

$$\frac{\langle I_{\omega}^2 \rangle}{\langle I_{shot}^2(\omega) \rangle} \simeq \frac{a}{N\pi\gamma_S\tau_e} \sim O(1) \quad (15)$$

where we wrote explicitly the dependence of the current fluctuation on N .

RANDOM SAMPLING

In the previous section we discussed the conditions in which the random orientation of the spins of the tunneling electrons can, through interaction with a single precessing spin, give a signal at the Larmor frequency. Nevertheless, this is only part of the picture. Since the tunneling electrons are probing a periodic precessional motion adiabatically, sequential tunneling and temporal correlations are essential for getting a signal with a narrow line width, as will be discussed below.

One of the most important characteristics of the signals detected with ESR-STM is their line width. The line width might reflect both the lifetime of the spin state and the back action effect of the tunneling electrons on the precessing spin. However, it is necessary to discuss an additional source of the line width that is directly related to the way in which we probe the precession.

We claim here that the periodic precession of the spin is sampled by the tunneling electrons. For each electron the precessing spin looks static (adiabatic process). The simplest case, which will be discussed here, is that in which the tunneling times of the tunneling electrons are uncorrelated. (As will be shown, this is not a realistic assumption.) In this case we can say that the sampling times obey an exponential distribution (Poisson process). We show here, using the $1/f$ spin noise model described above, that this is in accordance with the asymmetric line shapes observed in the experiments. Also, such a sampling process should lead to a rapid increase in the line width when the magnetic field is increased. The data published so far show such a trend.

We recall that in a tunneling current of 1 nA there are 6.25×10^9 electrons/s. The measurements were performed in a frequency of $2 - 8 \times 10^8$. This implies a ratio (R_s) of 0.033–0.13 of the average time between two tunneling electrons and the precession time. According to the Nyquist sampling theorem, it is impossible to

perform proper sampling of a periodic function if the sampling dwell time is above half of the time that it takes to complete one period. This is a fundamental limitation because it makes no sense to increase the field such that the precession frequency rises above 3×10^9 Hz (for a current of one nanoampere). However, it is anticipated that this should be important also in much smaller frequencies. Due to the uncorrelated nature of the tunneling current, it is expected that for a periodic function that is sampled randomly (according to the Poisson distribution), increasing the frequency means that more and more sampling times (between two consecutive tunneling events) will be larger than half of the period. This implies that at larger fields (or smaller currents) we expect that the line width will increase. Moreover, even in one peak we anticipate that the high frequency side will be broader than the low frequency side, which implies an asymmetric line shape that has a larger slope on the low frequency side. This is precisely the behavior that we see in the measurements.

Figures 2 and 3 show two spectra that were published already. Figure 2 shows a frequency-modulated signal that is taken from ref 24. The splitting in this signal was used to prove that the frequency depends on real time on the value of the magnetic field. However, it is easy to see that the original spectrum is asymmetric and distorted. A similar distortion is seen in the (already published) spectrum (Fig. 3). This spectrum was taken from ref 26. The shape of the spectrum is completely asym-

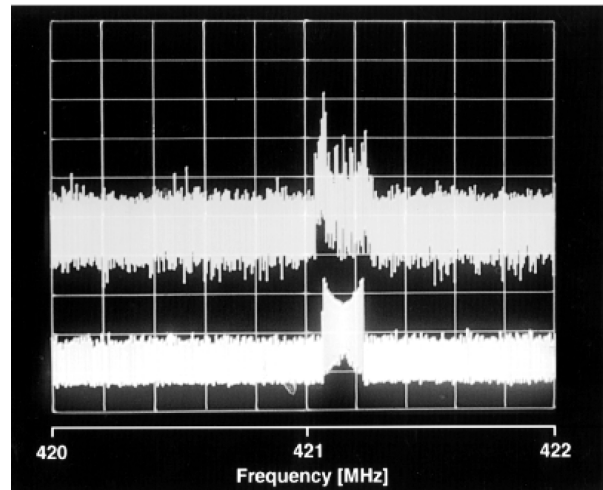


Fig. 2. A frequency modulated signal in a field of 150 G. The field modulation parameters are $\Delta H = 27$ mG and the modulation frequency is 300 KHz. Two spectra are presented. The upper spectrum is the data from the STM, the lower is a simulation. It is clear that the original line shape is not symmetric. Taken from ref 24.

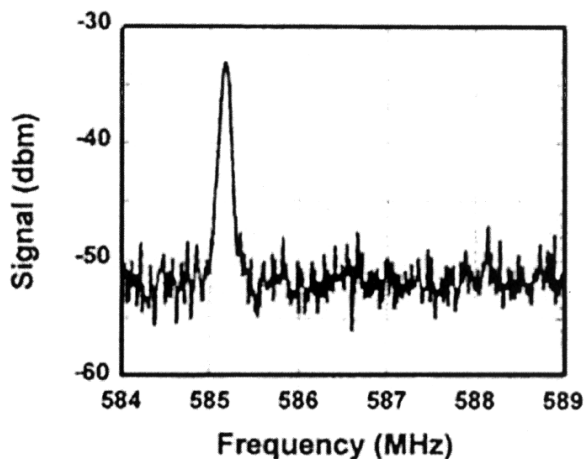


Fig. 3. An asymmetric ESR-STM spectrum of a BDPA cluster in a magnetic field of 210 G.²⁶

metric and looks very similar to the Poisson distribution function. As discussed in detail in ref 25, this asymmetric line shape is the cause of getting an absorption line shape when phase-sensitive detection is applied. The asymmetry was explained there as a rapid passage phenomenon. As will be shown here, we believe now that it can be explained by the physical nature of the measurement. It is important to emphasize that this is not always the case. Namely, other line shapes were also observed due to spectral diffusion. However, this represents the majority of cases.

In order to explain this trend we have done a very simple simulation. In this simulation we have estimated the value represented by eq 8. We have taken a sinusoidal function for S and a random function for I_s , which has a long time correlation ($1/f$ peak). However, in this simulation this function is sampled in times that are determined by the exponential distribution. After that, we estimated the power spectral density in the observed signal using the Welch method of spectral estimation.³⁸

This was done in a current of 1 nA and at the frequencies relevant for the experiment. Each spectrum was taken for a total acquisition time of 0.001 s. By changing the frequency we changed the average number of electrons for each period. For each such spectrum the power spectrum was calculated. Figure 4 shows the result of such a simulation for cases relevant to the experimental situation. It is clear that the calculated line widths are much larger than anticipated from lifetime considerations. The asymmetric line shapes observed are very similar to those observed from the experiment (compare with Fig. 3). A rapid increase in the line width is predicted (Fig. 5). The data we have so far support this

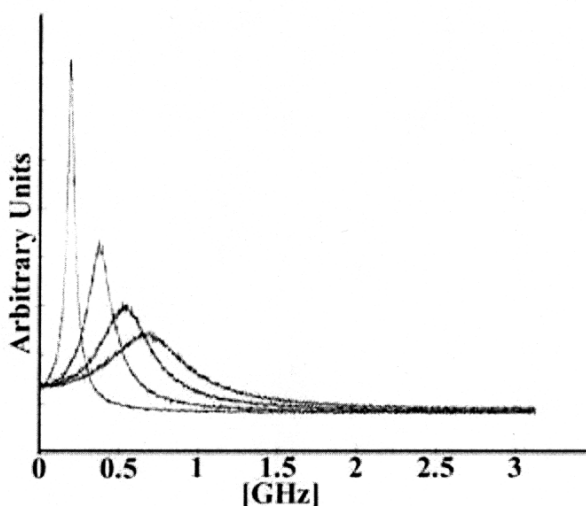


Fig. 4. The simulated line shapes for a periodic function that is accumulated with a Poisson distribution of sampling times. A current of 1 nA was assumed. The line shape is clearly asymmetric.

prediction, but more experiments are required (Fig. 6). Using longer lifetimes gives narrower line shapes but the overall behavior is the same. We want to emphasize that we do not take into account the back action effect of the tunneling electrons on the precessing spin. A similar behavior is expected when the tunneling current is reduced. However this may affect other things, and we think that the dependence of the line width on the field is a more informative measurement.

The line shape and line width that are shown in Figs. 4 and 5 were calculated with the $1/f$ spin noise

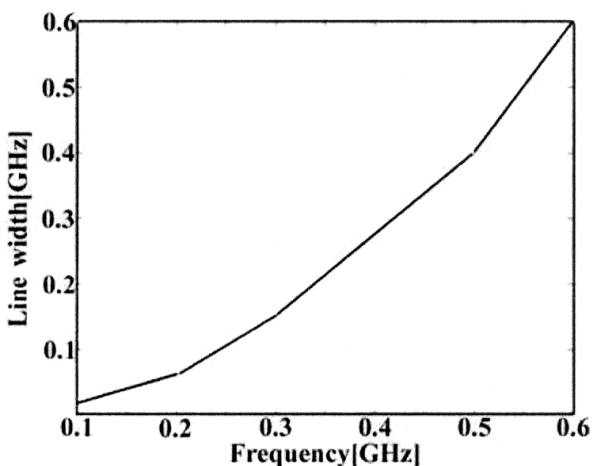


Fig. 5. The predicted line widths as a function of the magnetic field.

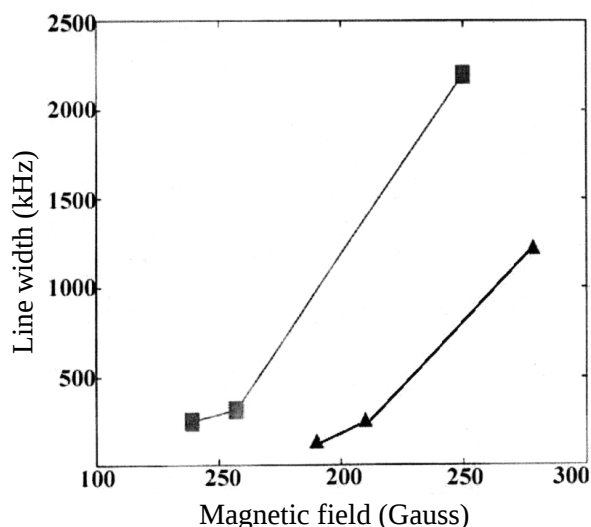


Fig. 6. The line widths as a function of the magnetic field. The upper curve is the line widths measured for Si Pb center,²³ while the lower curve is for BDPA molecules.³⁹

model, but the same results will be observed from other models as well. Sampling of a sinusoidal function at times given by an exponential distribution will give similar results.

It is clear that the calculated line widths are at least one order of magnitude larger than the experimental line widths. This difference reveals that the exponential distribution of sampling times is totally unrealistic. Because of the small size of the tunneling region in the STM tip, two electrons cannot tunnel at the same time because of the strong electrostatic repulsion between them. Thus the exponential distribution has to be modified such that some temporal correlations will be introduced in the tunneling times. We are currently trying to get more data on the line widths in different magnetic fields, currents and bias voltages, with the hope that ESR-STM line shapes and line widths will reveal details on the temporal correlations in the tunneling process.

CONCLUSION

We have proposed a $1/f$ noise as a mechanism of the coupling of tunneling current from the STM tip to localized spin S . This mechanism allows one to detect a signal from a single spin even in the case when there is *no dc spin polarization of the tunneling current*. Instead, we argue that the electric current will have a contribution coming from the coupling of spin fluctuating current to the local spin. The best way to detect a single spin in this approach is to perform a difference experiment where the noise spectrum is taken at the local spin site

and then at the nonmagnetic site elsewhere on the surface. The difference of two noise spectra would reveal the localized spin contribution. We find the signal-to-noise ratio for this model to be on the order of ~ 1 . We discussed the affect of random sampling times on the line widths. The results explain the asymmetric line shapes commonly observed with ESR-STM. The results predict a rapid increase of the line width with the field. The line widths calculated are too broad, which indicates that there must be correlations between the times of the tunneling events due to Coulomb repulsion. We think that line width measurements can provide a lot of information on the temporal nature of the tunneling process.

Acknowledgments. We are grateful to Z. Nussinov, J.X. Zhu, and A. Shnirman for useful discussions. This work was supported by a grant from the German-Israeli Foundation for Scientific Research and Development (GIF) and from LDRD at Los Alamos.

REFERENCES AND NOTES

- (1) Johnson, J.B. *Phys. Rev.* **1925**, 26, 71.
- (2) Voss, R.F.; Clarke, J. *Nature* **1975**, 258, 317.
- (3) Taft, B.A.; Hickey, B.M.; Wunsch, C.; Baker, D.J.Jr. *Deep Sea Res.* **1974**, 21, 403.
- (4) Wunsch, C. *Rev. Geophys. Space Phys.* **1972**, 10, 1.
- (5) Schottky, W. *Phys. Rev.* **1926**, 28, 74.
- (6) Dutta, P.; Dimon, P.; Horn, P.M. *Phys. Rev. Lett.* **1979**, 43, 646.
- (7) Dutta, P.; Horn, P.M. *Rev. Mod. Phys.* **1981**, 53, 497.
- (8) Möller, R.; Esslinger, A.; Koslowski, B. *Appl. Phys. Lett.* **1989**, 55, 2360.
- (9) Möller, R.; Esslinger, A.; Koslowski, B. *J. Vac. Sci. Technol.* **1990**, A 8, 590.
- (10) Möller, R.; Baur, C.; Esslinger, A.; Kürz, P. *J. Vac. Sci. Technol. B* **1991**, 9, 609.
- (11) Maeda, K.; Sugita, S.; Kurita, H.; Uota, M.; Uchida, S.; Hinomuro, M.; Mera, Y. *J. Vac. Sci. Technol. B* **1994**, 12, 2140.
- (12) Hooge, F.N. *Phys. Lett. A* **1969**, 29, 139.
- (13) Ocio, M.; Bouchiat, M.; Monod, P. *J. Magn. Magn. Mater.* **1986**, 54–57, 11.
- (14) Koch, R.H.; Reim, W.; Malozemoff, A.P.; Ketchen, M.B. *J. Appl. Phys.* **1987**, 61, 3678.
- (15) Weissman, M.B.; Israeloff, N.E. *J. Appl. Phys.* **1990**, 67, 4884.
- (16) Woods, S.I.; Kirtley, J.R.; Sun, S.; Koch, R.H. *Phys. Rev. Lett.* **2001**, 87, 137205.
- (17) Podzorov, V.; Vehara, M.; Gershenson, M.E.; Koo, T.Y.; Cheong, S.-W. *Phys. Rev. B* **2000**, 61, R3784.
- (18) Raquet, B.; Viret, M.; Coster, M.; Baibich, M.; Pannetier, M.; Blanco-Mantecon, M.; Rakoto, H.; Maignan, A.; Lambert, S.; Fermon, C. *J. Magn. Magn. Mater.* **2003**, 258–259, 119.
- (19) Griswold, T.W.; Kip, A.F.; Kittel, C. *Phys. Rev.* **1952**, 88, 951.

- (20) Feher, G.; Kip, A. *Phys. Rev.* **1955**, 98, 337.
- (21) Dyson, F.J. *Phys. Rev.* **1955**, 98, 349.
- (22) Manassen, Y.; Hamers, R.J.; Demuth, J.E.; Castellano, A.J.Jr. *Phys. Rev. Lett.* **1989**, 62, 2531.
- (23) Manassen, Y.; Ter-Ovanesyan, E.; Shachal, D.; Richter, S. *Phys. Rev. B* **1993**, 48, 4887.
- (24) Manassen, Y. *J. Magn. Reson.* **1997**, 126, 133.
- (25) Manassen, Y.; Mukhopadhyay, I.; Ramesh Rao, N. *Phys. Rev. B* **2000**, 61, 16223.
- (26) Durkan, C.; Welland, M.E. *Appl. Phys. Lett.* **2002**, 80, 458.
- (27) Manoharan, H.C. *Nature* **2002**, 416, 24.
- (28) Berman, G.P.; Brown, G.W.; Hawley, M.E.; Tsifernovich, V.I. *Phys. Rev. Lett.* **2001**, 87, 097902-1.
- (29) Mozyrsky, D.; Fedichkin, F.; Gurvitz, S.A.; Berman, G.P. *Phys. Rev. B* **2002**, 66, 161313.
- (30) Balatsky, A.V.; Manassen, Y.; Salem, R. *Philos. Mag. B* **2002**, 82, 1291.
- (31) Balatsky, A.V.; Manassen, Y.; Salem, R. *Phys. Rev. B* **2002**, 66, 195416.
- (32) Zhu, J.X.; Balatsky, A.V. *Phys. Rev. Lett.* **2002**, 89, 286802.
- (33) Balatsky, A.V.; Martin, I. cond-mat/01122407.
- (34) Levitov, L.S.; Rashba, E.I. *Phys. Rev. B* **2003**, 67, 115324.
- (35) Nussinov, Z.; Crommie, M.F.; Balatsky, A.V. *Phys. Rev.* **2003**, B 68, 085402.
- (36) Bulaevskii, L.; Hruska, M.; Ortiz, G. *Phys. Rev. B* **2003**, 68, 125415.
- (37) Shnirman, A.; Mozyrsky, D.; Martin, I. cond-mat/0211618.
- (38) Welch, P.D. "The Use of Fast Fourier Transform for the Estimation of Power Spectra: A Method Based on Time Averaging over Short, Modified Periodograms". *IEEE Trans. Audio. Electroacoust* **1967**, AU-15, 70.
- (39) Durkan, C. *Contemp. Phys.* **2004**, 451.